BGY32 BGY33 BGY35 BGY36

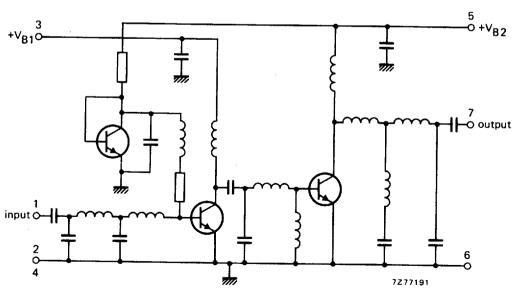
VHF POWER AMPLIFIER MODULES

A range of broadband amplifier modules designed for mobile communications equipments, operating directly from 12 V vehicle electrical systems. The devices will produce 18 W output into a 50 Ω load. The modules consist of a two stage RF amplifier using npn transistor chips, together with lumped-element matching components.

QUICK REFERENCE DATA

type number	mode of operation	frequency range f (MHz)	nominal supply voltages V _{B1} = V _{B2} (V)	power	load power PL (W)	nominal input impedance z _i (Ω)	nominal load impedance Z _L (Ω)
BGY32	cw	68 to 88	12.5	100	> 18 typ 23	50	50
BGY33	cw	80 to 108	12.5	100	> 18 typ 22	50	50
BGY35	cw	132 to 156	12.5	150	> 18 typ 22	50	50
BGY36	cw	148 to 174	12.5	150	> 18 typ 21	50	50

CIRCUIT DIAGRAM



PRODUCT SAFETY This device incorporates beryllium oxide, the dust of wich is toxic. The device is entirely safe provided that the BeO disc is not damaged.

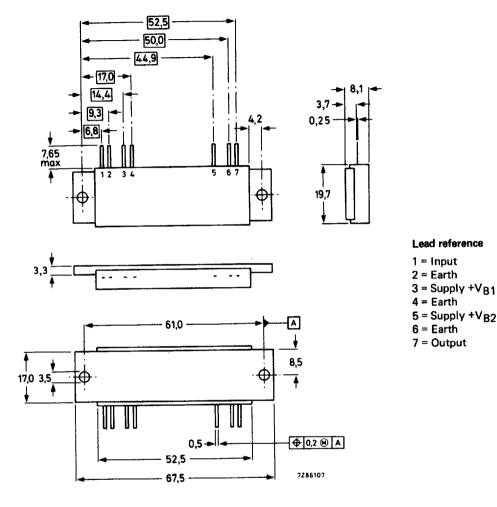
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Dimensions in mm

₩ 6653931 0030212 3T3 **■** APX

MECHANICAL DATA

Fig. 1 SOT132B.



Mounting and soldering recommendations

To ensure good thermal transfer the module should be mounted using heatsink compound onto a heatsink with a flat surface; if an isolation washer is used heatsink compound should be used on both sides of the insulator. Burrs and thickening of the holes in the heatsink should be removed and 3 mm bolts tightened to torques of 0,5 Nm minimum.

Devices may be soldered directly into a circuit with a soldering iron at maximum iron temperature of 245 °C for 10 seconds at least 1 mm from the plastic.

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VHF power amplifier modules

X9A **1**ES E150600 1EPE340

BGY32 BGY33 BGY35 BGY36

RATINGS

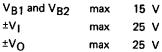
Limiting values in accordance with the Absolute Maximum System (IEC 134)

DC voltages (with respect to flange)

DC supply terminals
RF input terminal
RF output terminal

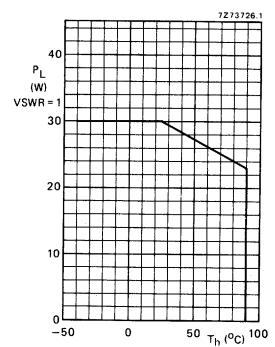
Input drive power BGY32 and BGY33
Input drive power BGY35 and BGY36

Load power



 $\pm v_O$ max 25 V P_D max 200 mW

P_D max 300 mW P_L max 30 W



Storage temperature range
Operating heatsink temperature

T_{stg} T_h

-40 to 100 °C

max

90 °C

t - - - - l - - - - - l - - - - - -

CHARACTERISTICS

$$T_{h} = 25 \, {}^{\circ}C$$

Quiescent current			BGY32	BGY33	BGY35	BGY36	
$V_{B1} = V_{B2} = 12,5 \text{ V; } P_D = 0;$ $R_S = R_L = 50 \Omega$	I _{BQ1}	typ typ	6 13	6 13	6 13	6 13	mA mA
Frequency range	f	> <	68 88	80 108	132 156	1 -	MHz MHz
Load power $V_{B1} = V_{B2} = 12.5 \text{ V}; R_S = R_L = 50 \Omega$ BGY32 and BGY33; $P_D = 100 \text{ mW}$	P _L	> typ >	18 23 40	18 22 40	-	-	W W %
	PL	typ > typ	50 –	50	18 22	18 21	% W W
BGY35 and BGY36; P _D = 150 mW	η	> typ	-	_	40 50	40 50	

Harmonic output

Any single harmonic will be at least 25 dB down relative to carrier

Input VSWR with respect to 50 Ω

typ

1,5

Stability

The module is stable with a load VSWR up to 3:1 (all phases) when operated within the following conditions: V_{S1} = 6 to 15 V; V_{S2} = 10 to 15 V; $V_{S1} \le V_{S2}$; P_D = 50 to 200 mW; frequency within operating frequency range, provided the maximum ratings of the module are not exceeded.

Ruggedness

The modules are capable of withstanding load mismatch of up to 50 VSWR for short period overload conditions, with PD, VB1 and VB2 at maximum values providing the combination does not result in the matched RF output power rating being exceeded.

APPLICATION INFORMATION

Supply

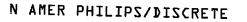
An electrolytic capacitor of 10 μ F (25 V), in parallel with a polyester capacitor of 100 nF to earth, is recommended as decoupling arrangement for each power supply pin.

Power rating

In general it is recommended that the output power from the module under nominal design conditions should not exceed 23 W in order to provide adequate safety margin under fault conditions.

Output power control

The module is not designed to be operated over a large range of output power levels. The purpose of the output power control is to set the nominal output power level. The preferred method of output power control is by varying the drive power between 50 and 200 mW. The next option is by varying VS1 between 6 and 12.5 V.

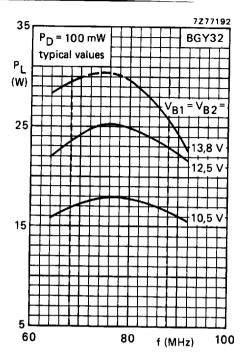


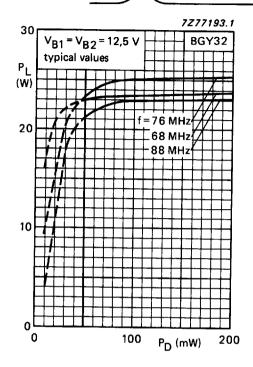
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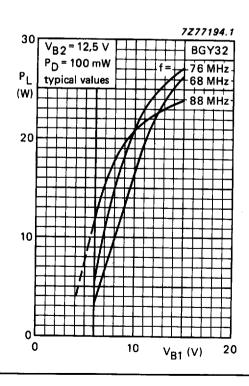
VHF power amplifier modules

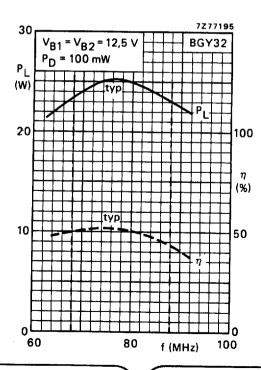
XAV = 0030512 005 = Abx

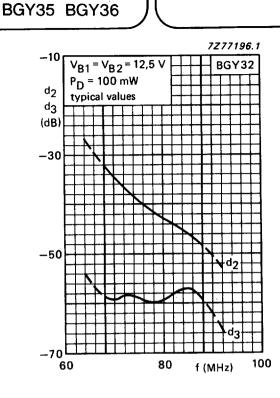
BGY32 BGY33 BGY35 BGY36

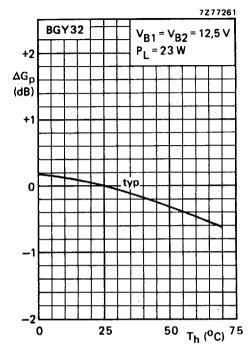


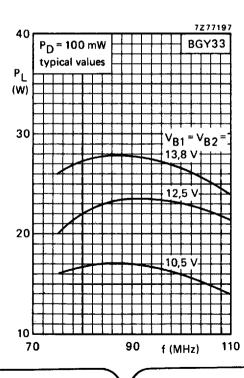


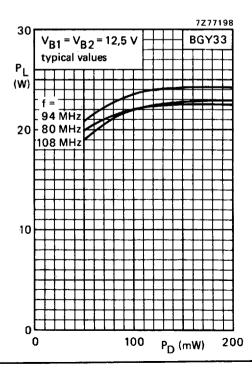


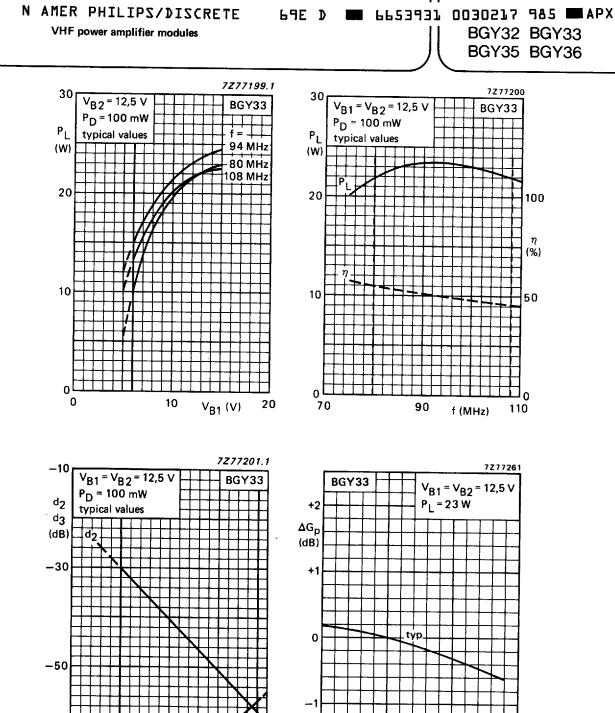












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90

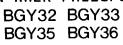
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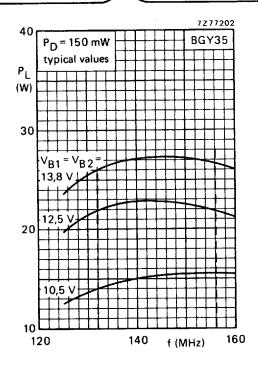
f (MHz)

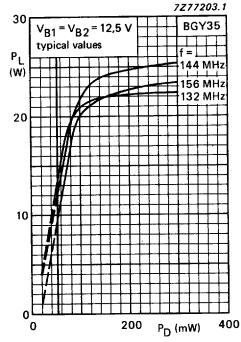
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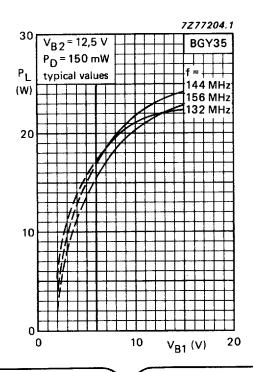
25

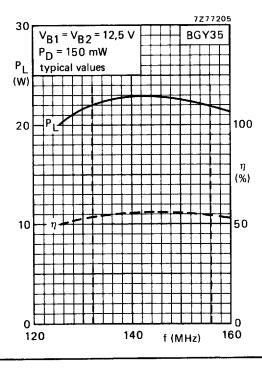
⁵⁰ T_h (°C) ⁷⁵



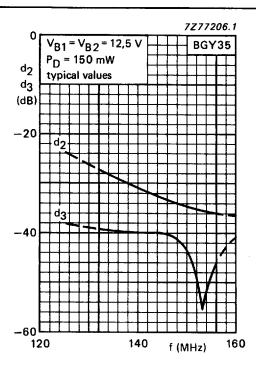


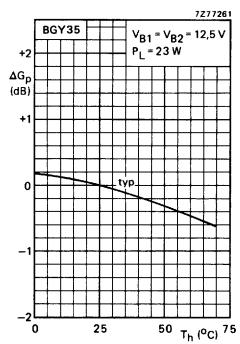


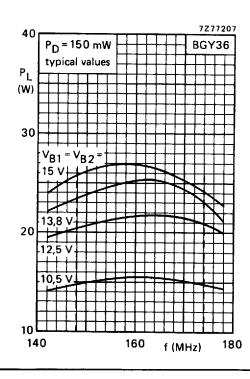


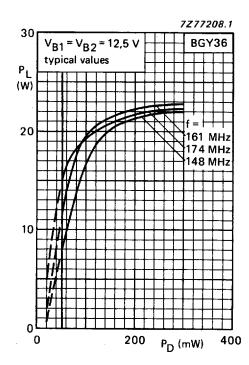


BGY32 BGY33 BGY35 BGY36

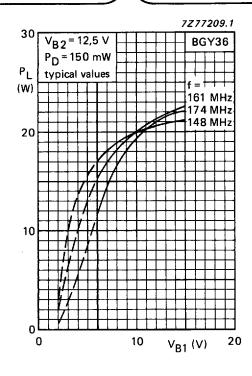


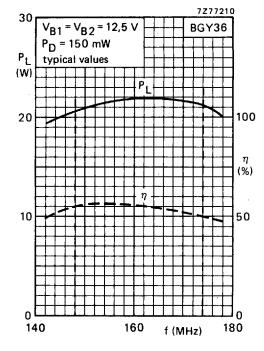


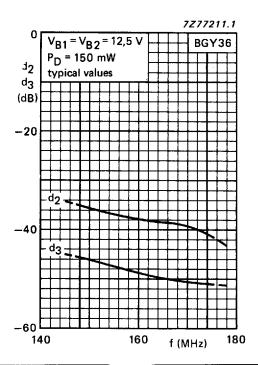


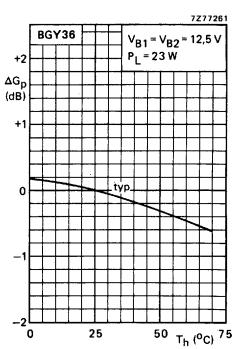


BGY32 BGY33 BGY35 BGY36









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